

Hybrid Integrated Photonics for Coherent LiDAR

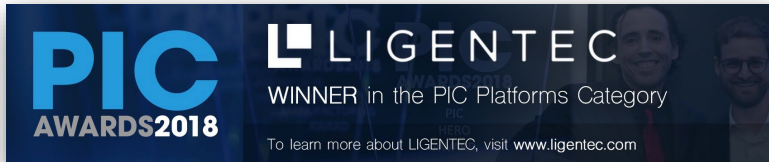
Anton Lukashchuk, EPIC meeting, ESA, 13 Sept

EPFL

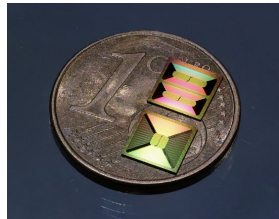


Technology development @ EPFL

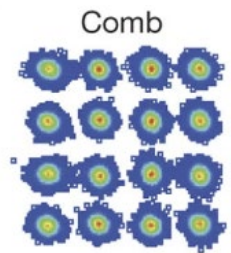
Milestones & achievements



2016
Development of
ultra-low loss
SiN platform¹



2017
Demonstration of
telecom
applications² and
hybrid integrated
SIL laser³

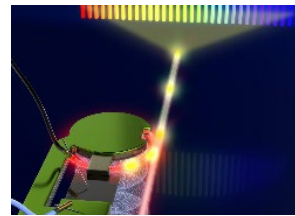


BER = 6.7×10^{-5}

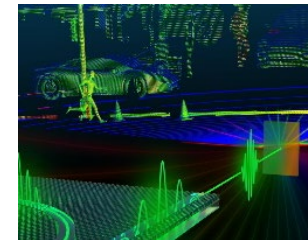
2018
First fully
integrated
optical
frequency comb³



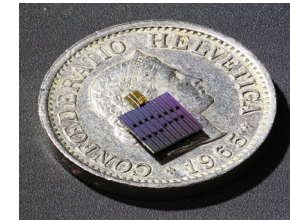
2018 – 2019
Development of
piezoelectric
actuators
monolithically
integrated with SiN
PICS^{4,5}



2020
Demonstration of
frequency-agile
optical frequency
comb⁶⁻⁷ and comb-
based FMCW
LiDAR⁶⁻⁸



2021
Development of
frequency-agile
laser⁹



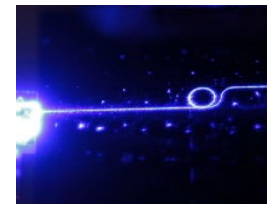
2022
Industrialization of
frequency-agile
lasers:
RSOAs & PZT
actuators

Blue laser¹⁰

Demonstration of
thin-film SiN
platform

Development of
LNOI platform

Electro-optical
hybrid integration



[1] M. Pfeiffer et al. *Optica* 3(1) (2016)

[2] P. Marin-Palomo et al. *Nature* 546 (2017)

[3] A. Raja et al. *Nature comm.* 10(1) (2019)

[4] H. Tian et al. *Nature comm.* 11(1) (2020)

[5] J. Liu et al. *Nature* 583(7816) (2020)

[6] A. Voloshin et al. *Nature comm.* 12(1) (2021)

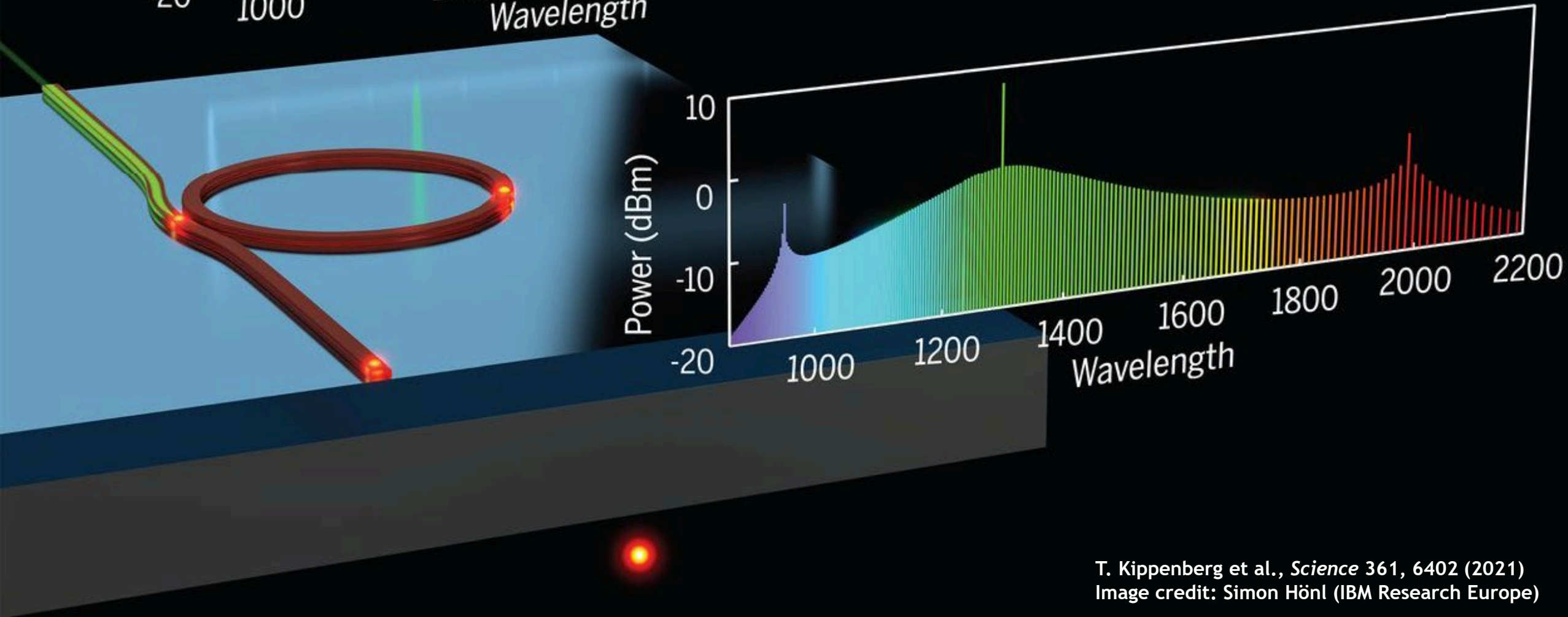
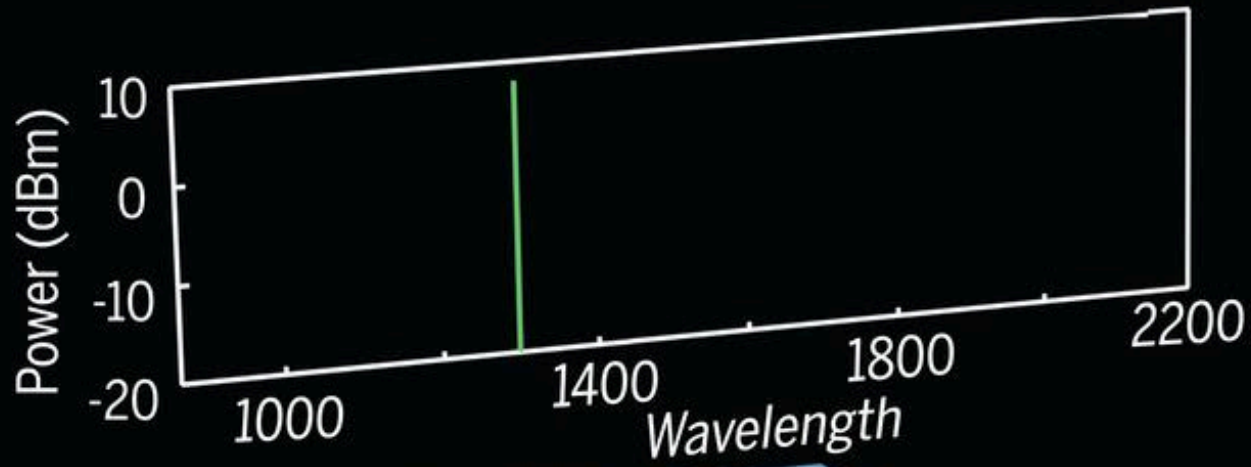
[7] J. Liu et al. *Nature comm.* 12(1) (2021)

[8] J. Riemensberger et al. *Nature* 581(7807) (2020)

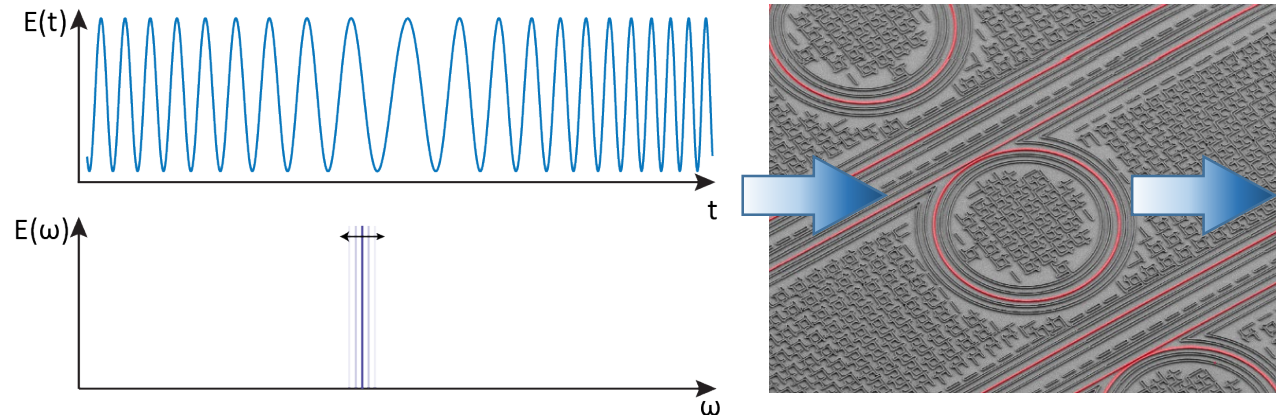
[9] G. Lihachev et al. *Nature comm.* 13(1) (2022)

[10] A. Siddharth *APL Photonics* 7(046108) (2022)

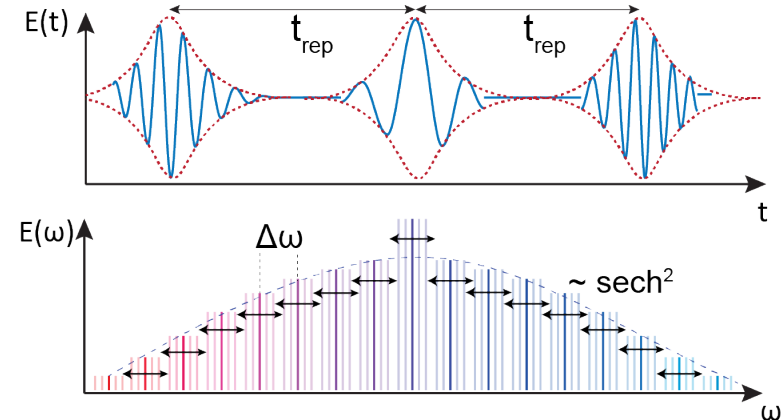
Chip-scale Optical Frequency Combs



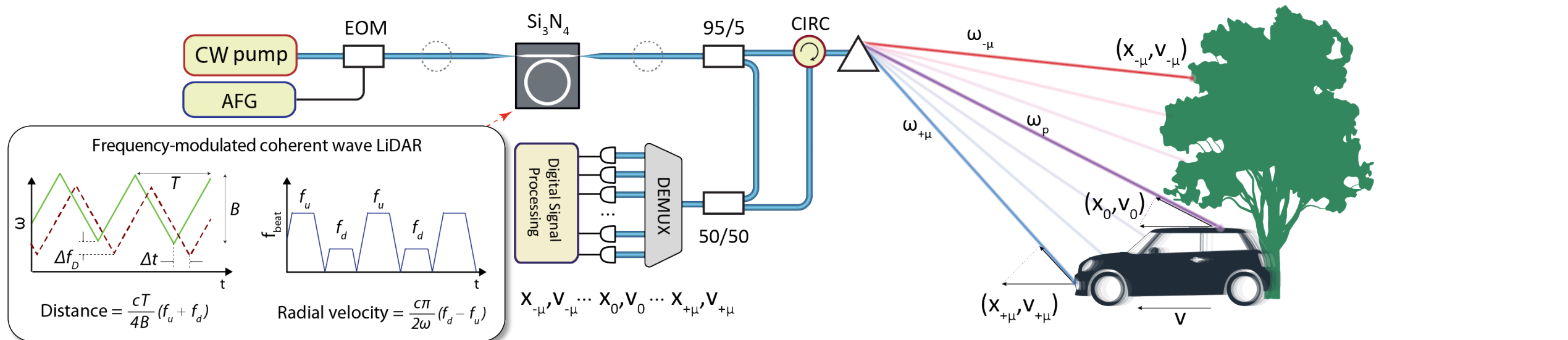
Massively parallel coherent laser ranging using soliton microcombs



Single-wavelength FMCW laser

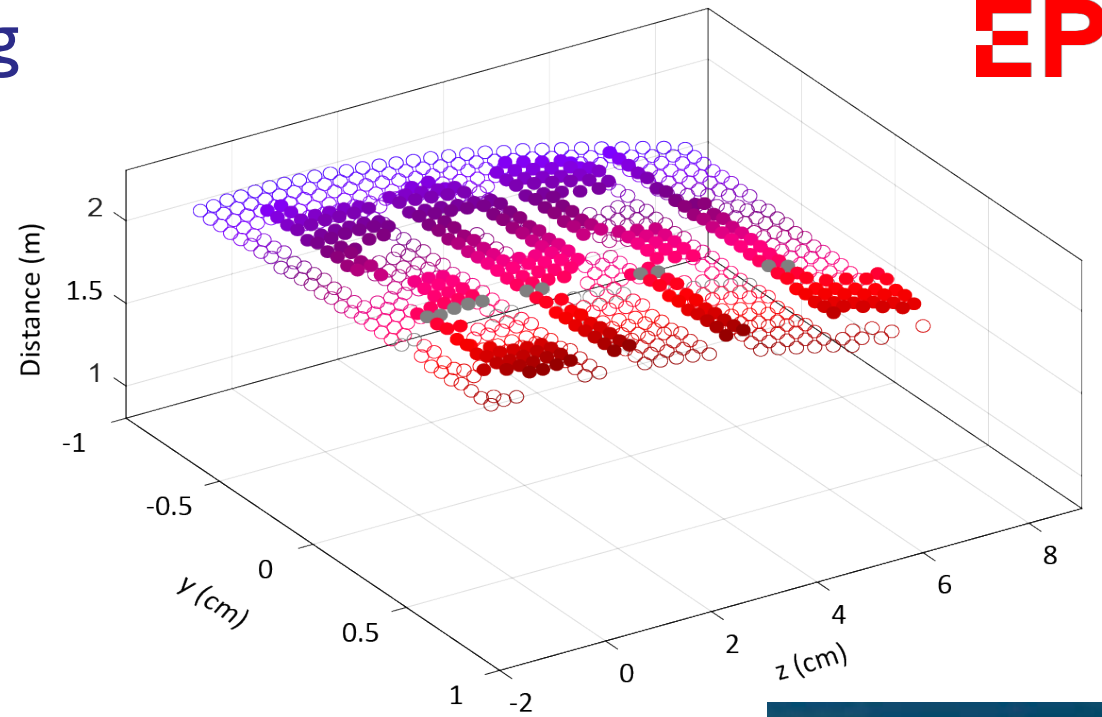
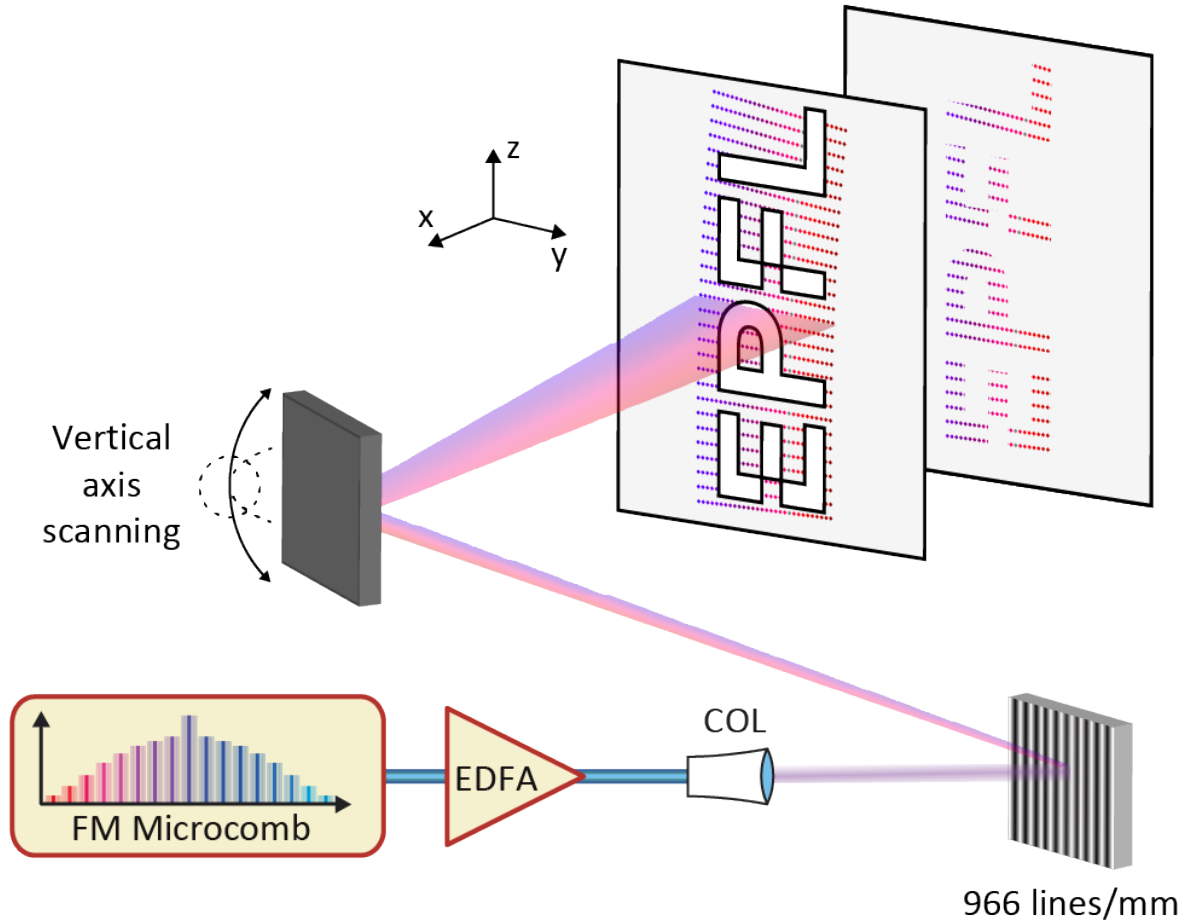


Coherent multi-wavelength FMCW laser



Massively parallel coherent laser ranging

EPFL



**Cover article of
Nature issue
14th May 2020**



Hybrid Aluminium Nitride / PZT MEMS - Si₃N₄ PIC Technology

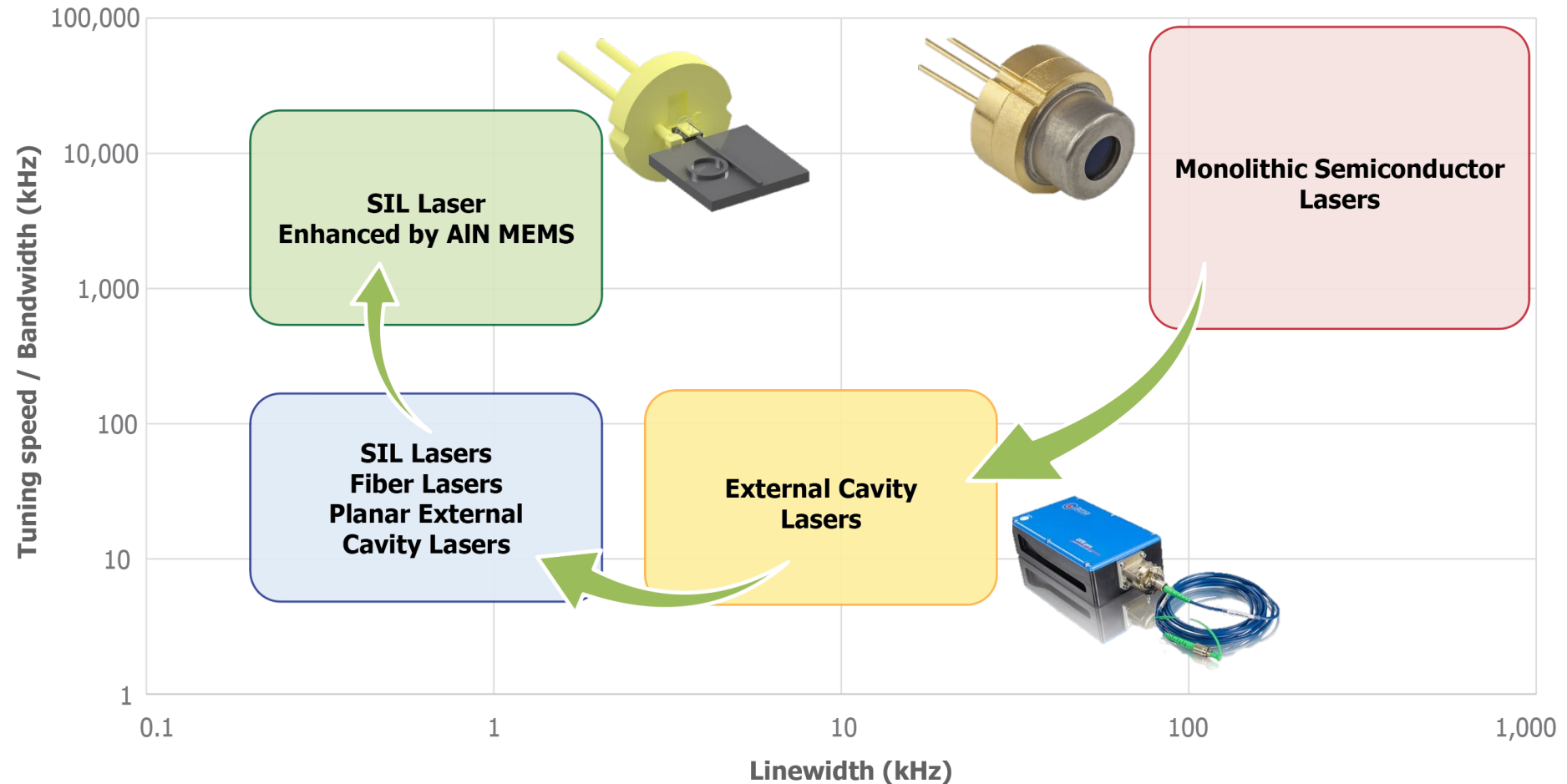


Advantages:

- high actuation linearity,
- no hysteresis, high power handling (breakdown field > 100 V/μm)
- low current leakage (~2 nA)
- Cryogenic compatibility
- Combines wafer scale, established MEMS processing, with PIC wafer scale manufacturing

The logo for DEEP Light, featuring the word 'DEEP' in a large, blue, sans-serif font with a grid pattern to its left, and the word 'Light' in a smaller, blue, sans-serif font below it.

Eliminating the **trade-off** between **tunability** and **narrow linewidth** lasing **EPFL**



Piprek, Joachim, and John E. Bowers. "Analog modulation of semiconductor lasers." Vol. 234, Cambridge Univ. Press (2002)

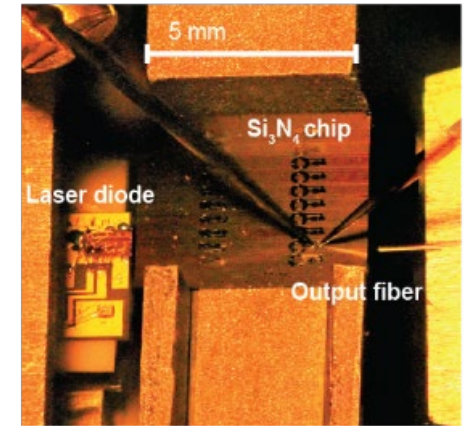
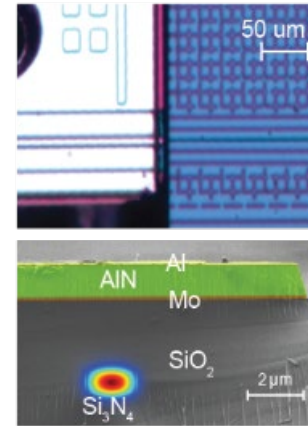
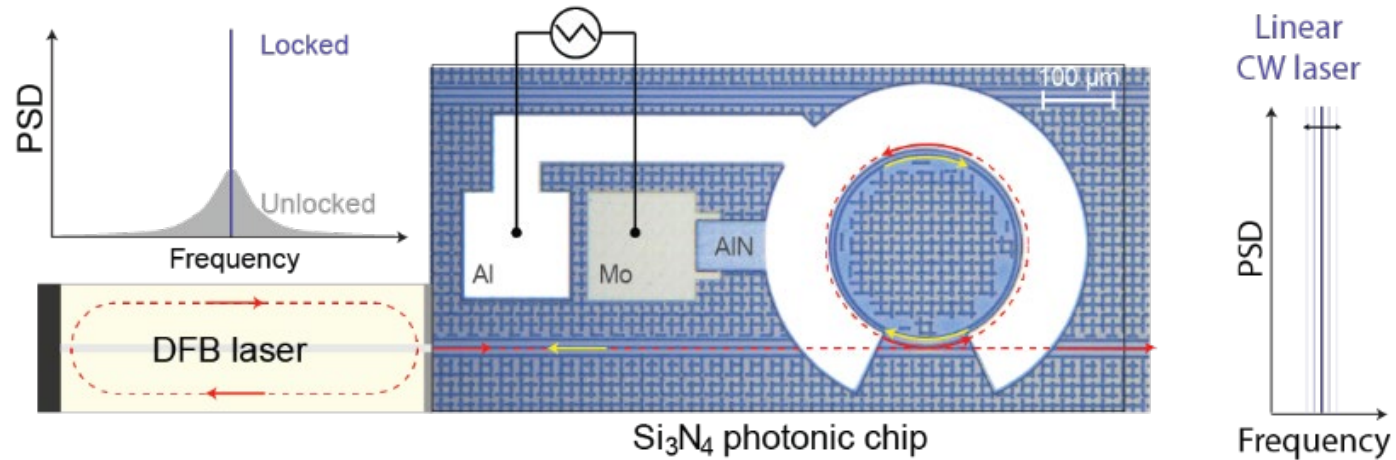
Mroziewicz, B. "External cavity wavelength tunable semiconductor lasers - a review." *Opto-Electronics Review*, 16.4 (2008)

Zorabedian, Paul. "Tunable external-cavity semiconductor lasers." *Tunable Lasers Handbook*. Academic Press, 349-442 (1995)

Liang, W., et al. "Ultralow noise miniature external cavity semiconductor laser." *Nature communications* 6.1 (2015)

Numata, Kenji, et al. "Performance of planar-waveguide external cavity laser for precision measurements." *Optics Express* 18.22 (2010)

Self-injection locking of semiconductor laser diodes



Self-injection locking bandwidth:

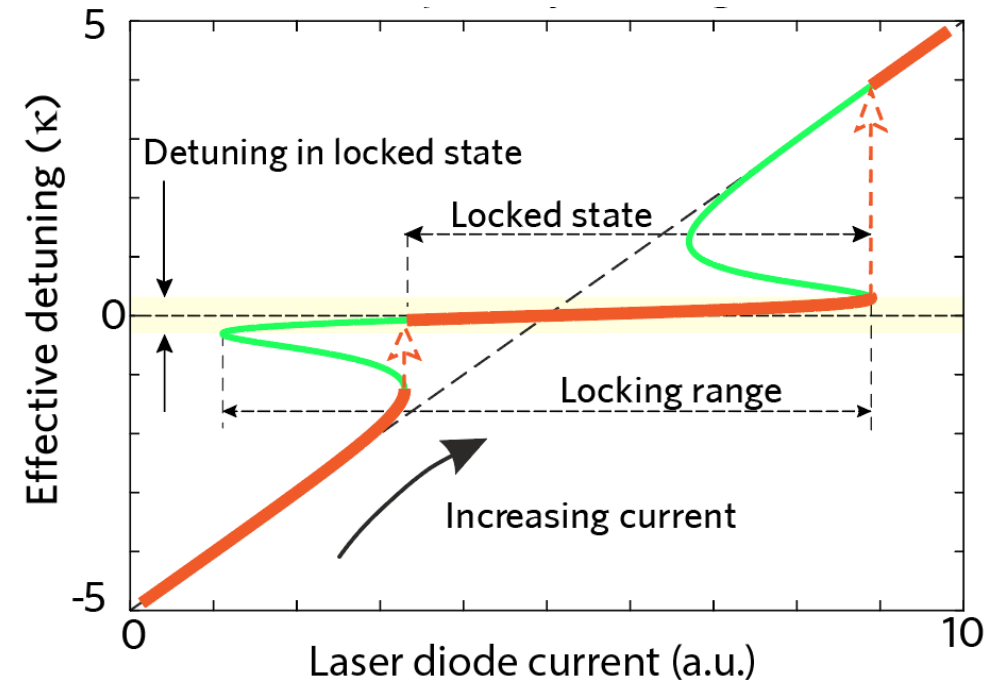
$$\frac{\Delta\omega_{lock}}{\omega} \approx \sqrt{1 + \alpha_g^2} \frac{\Gamma_m}{Q_d}$$

Assuming strong backreflection Γ_m

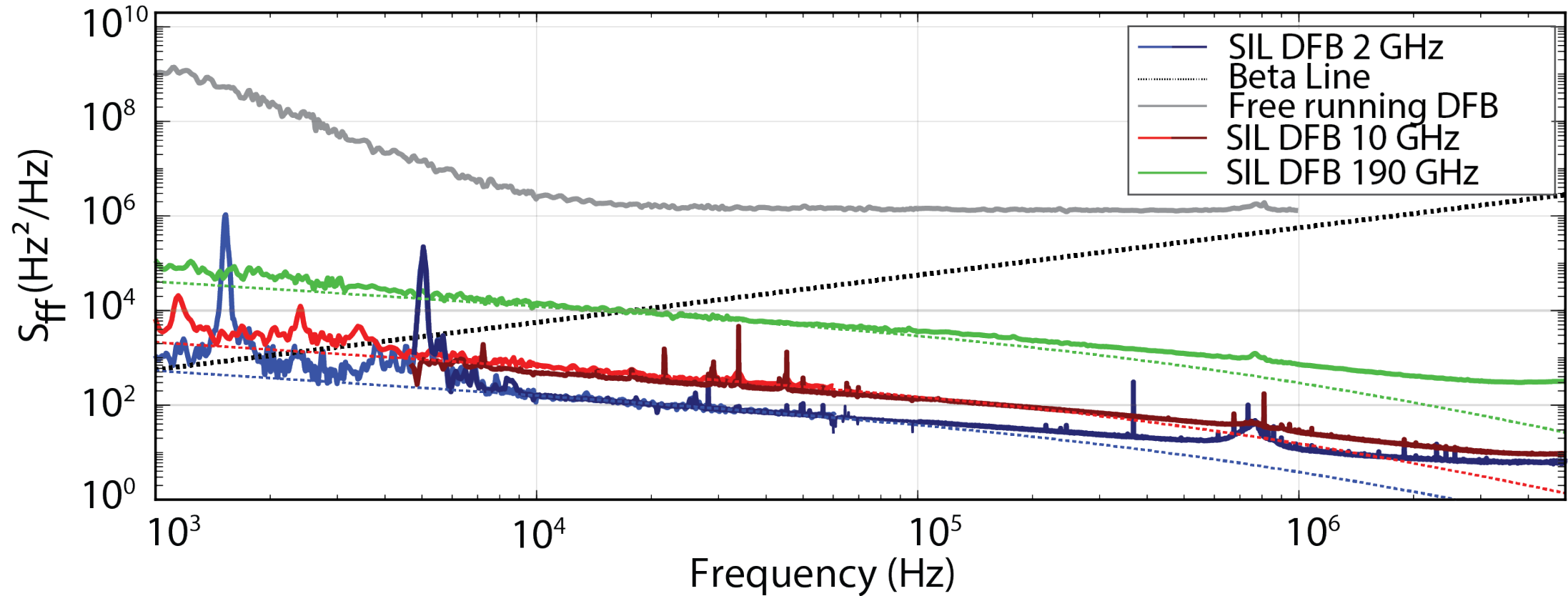
Laser linewidth reduction:

$$\frac{\delta\omega}{\delta\omega_{free}} \approx \frac{Q_d^2}{Q_m^2} \frac{1}{16\Gamma_m^2(1 + \alpha_g^2)}$$

Assuming white frequency noise

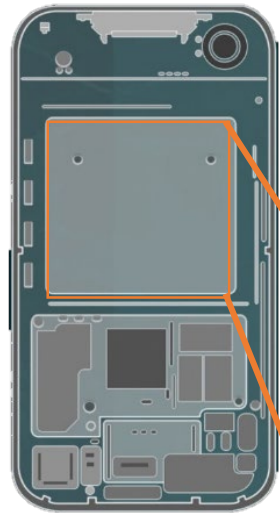


Frequency noise of Photonic Damascene SIL

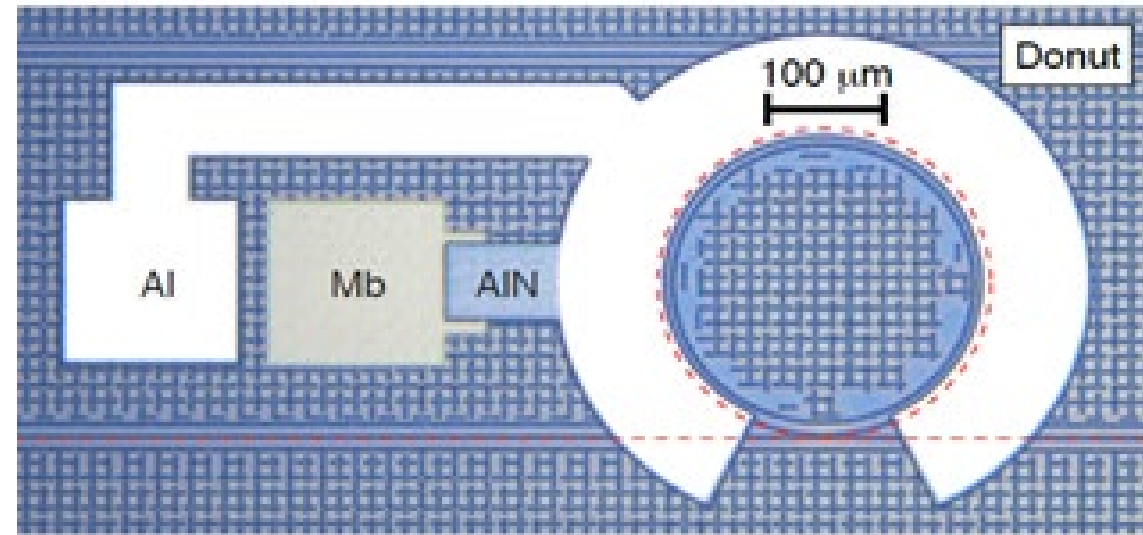
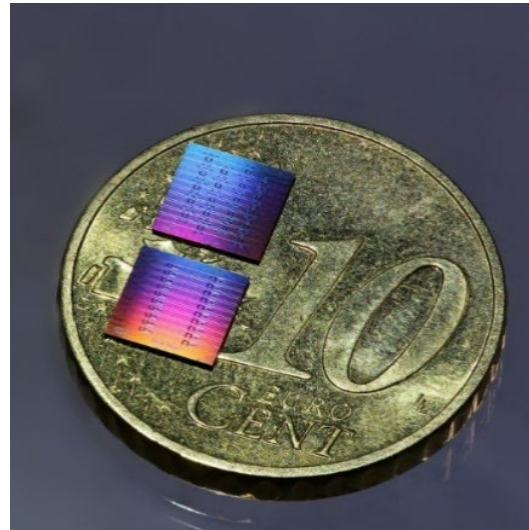
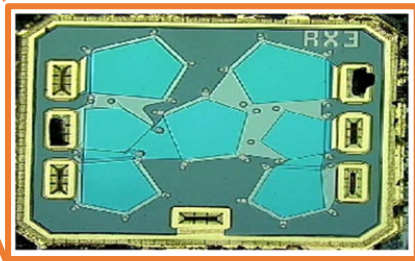


- Frequency noise limited by thermo-refractive noise of high confinement microresonator
- Lorentzian linewidth: 600 Hz (190 GHz), 40 Hz (10 GHz), 25 Hz (2 GHz)

Core Technology: Piezoelectric MEMS actuators

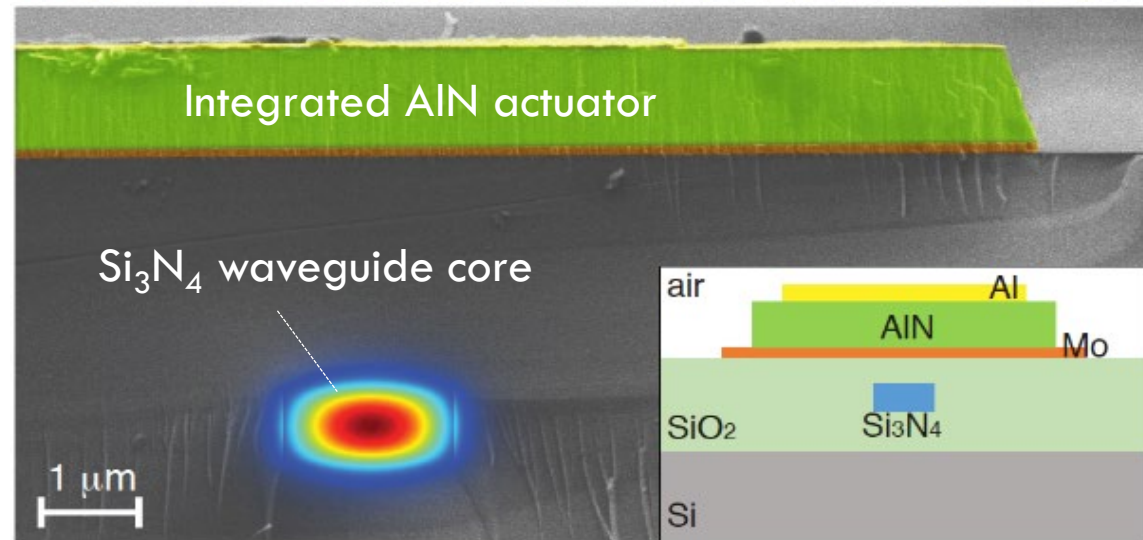


RF filters in cell phones: Thin-film bulk acoustic resonators



Proven MEMS technology based on piezoelectric materials AlN, PZT

- Available foundry processes (BEOL process)
- Monolithic integration
- Compatible with Si_3N_4 PIC
- Highly linear, no hysteresis, low power



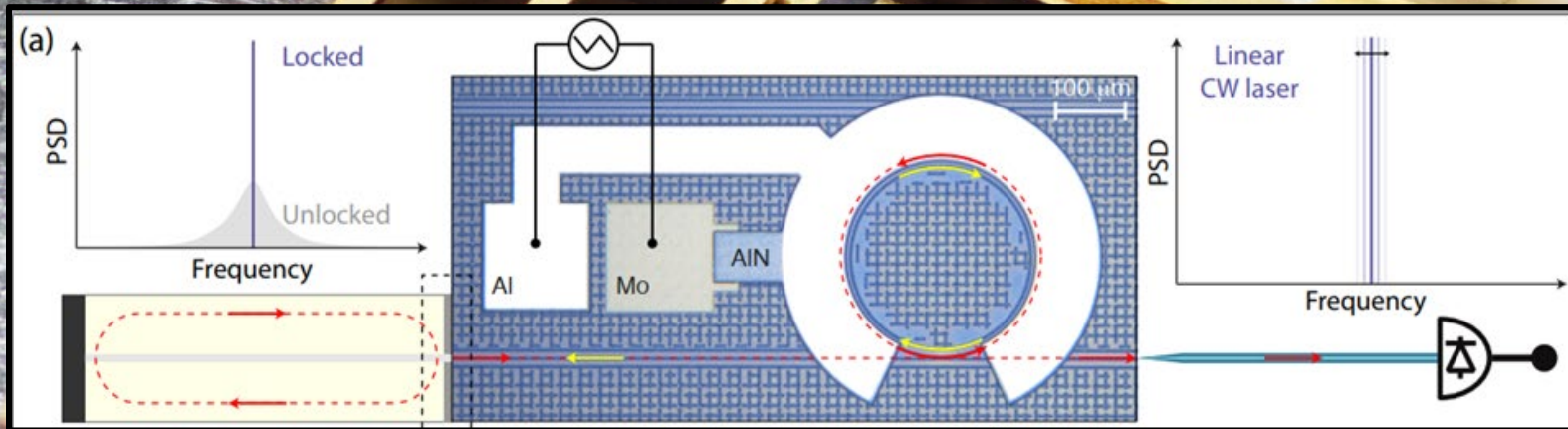
Technology Demonstrators

DEEP Light

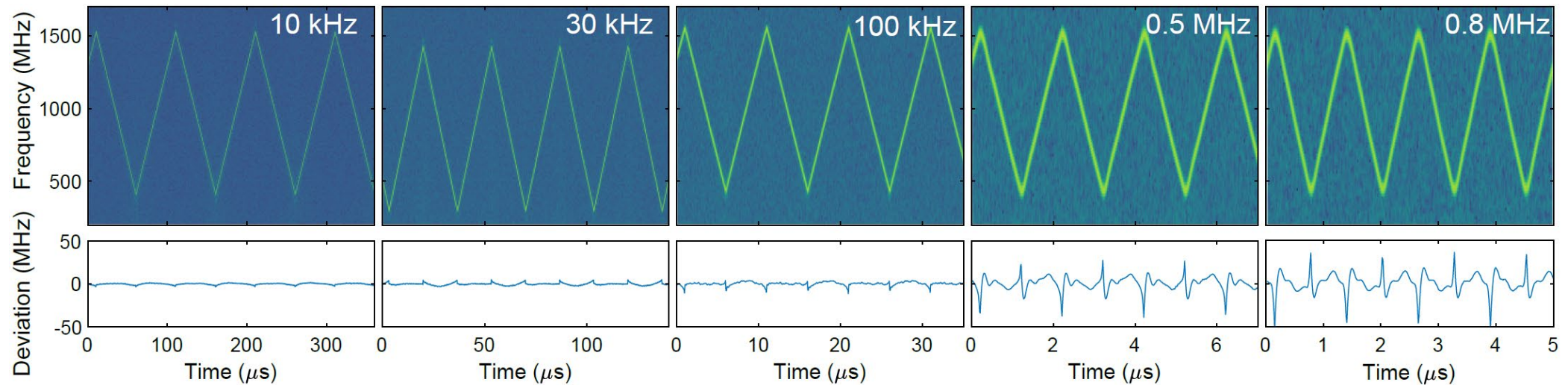
Laser diode

Si_3N_4 PIC + AlN actuator

SMF



Performance of Frequency-Agile SIL Lasers

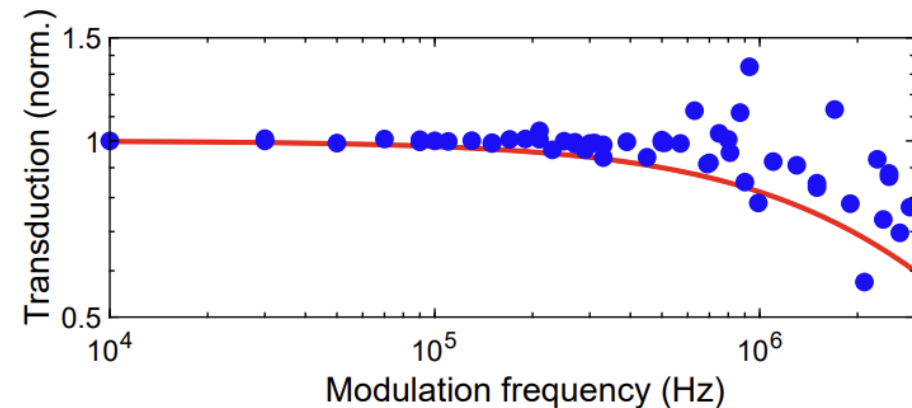


AIN actuators:

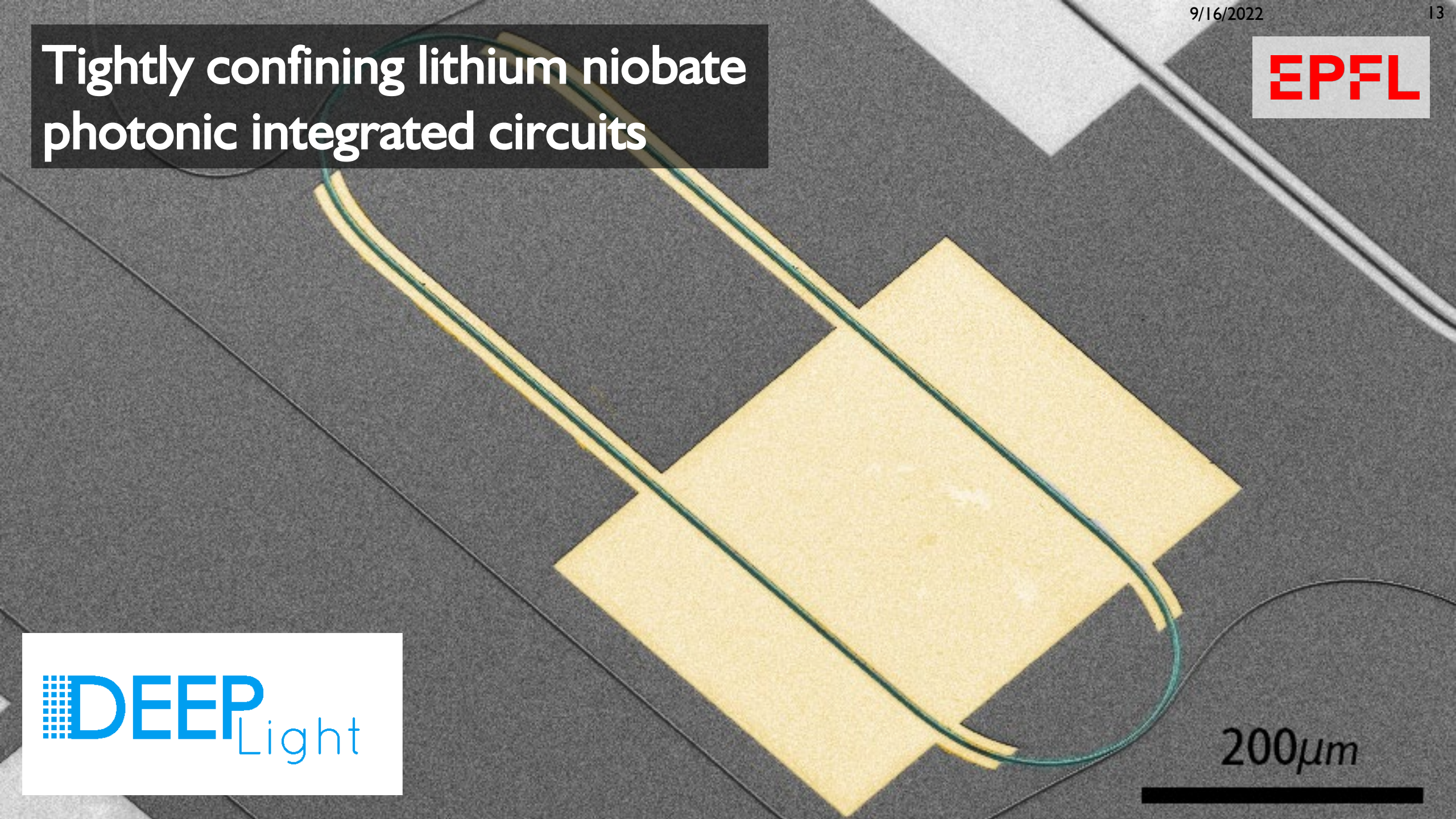
- > 1 GHz tuning at 1 MHz sweep rate, tuning efficiency ~ 20 MHz/V
- Frequency actuation bandwidth: > 10 MHz
- Flat frequency actuation bandwidth: > 0.8 MHz (RMS nonlinearity $< 0.1\%$ @ 10 kHz sweep rate)

PZT actuators:

- > 1 GHz tuning at 100 kHz sweep rate, tuning efficiency ~ 400 MHz/V
- Frequency actuation bandwidth: > 1 MHz
- RMS nonlinearity $< 0.3\%$ @ 10 kHz sweep rate (for 90% of sweep)



Tightly confining lithium niobate photonic integrated circuits

EPFL**DEEP**Light200 μ m

Ultra-low loss thin film lithium niobate photonics

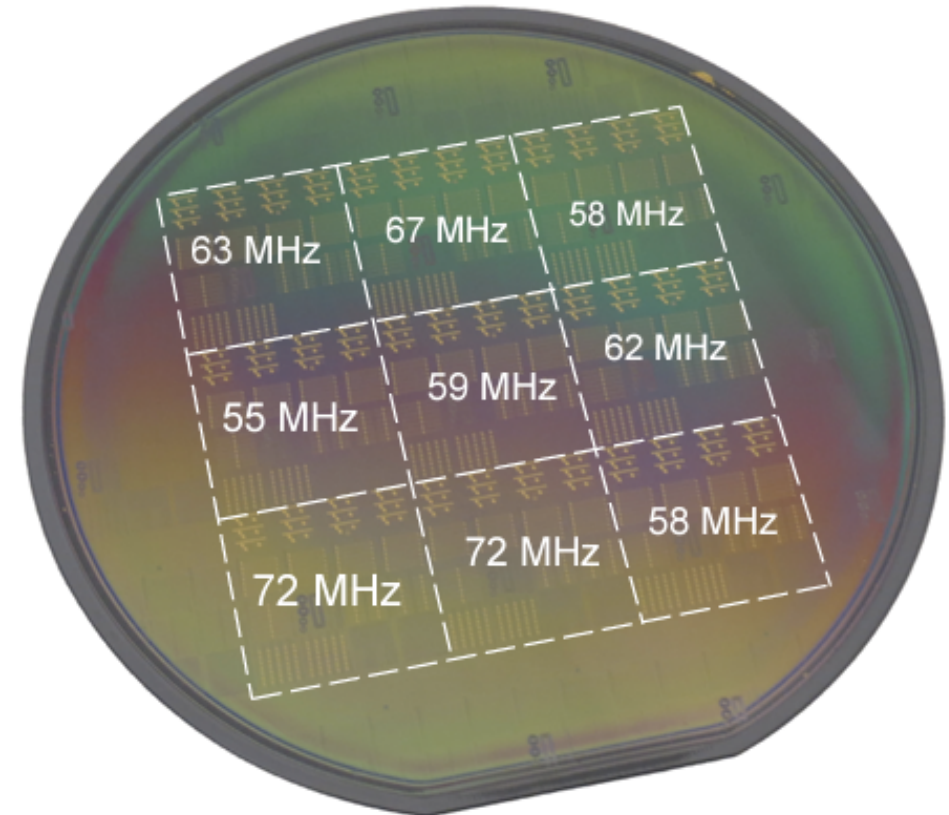
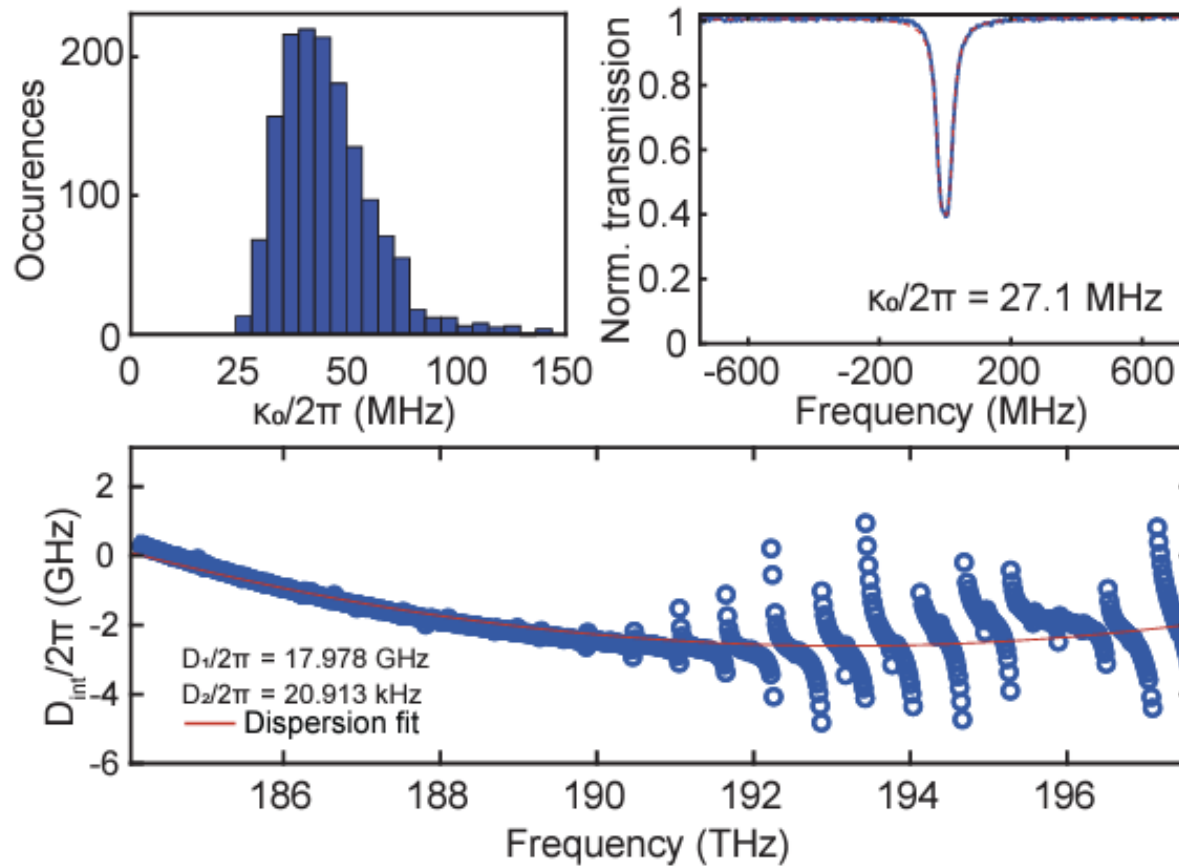


Lithium Niobate was once hailed as the “Silicon of Photonics”...

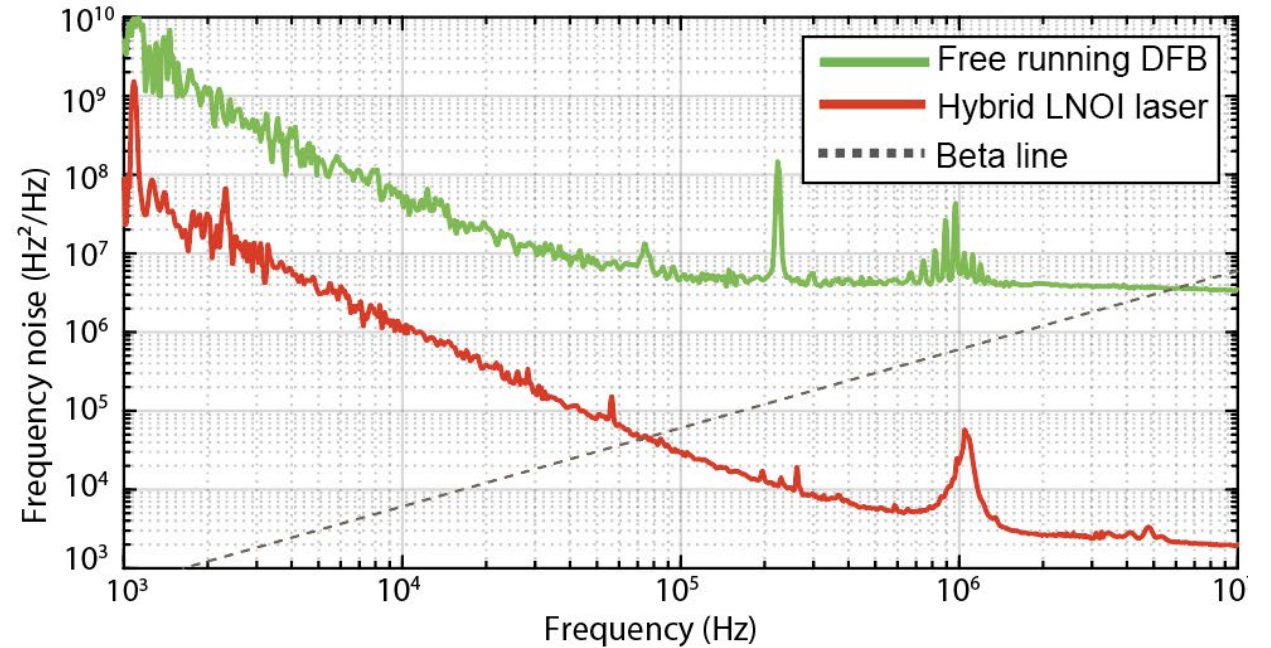
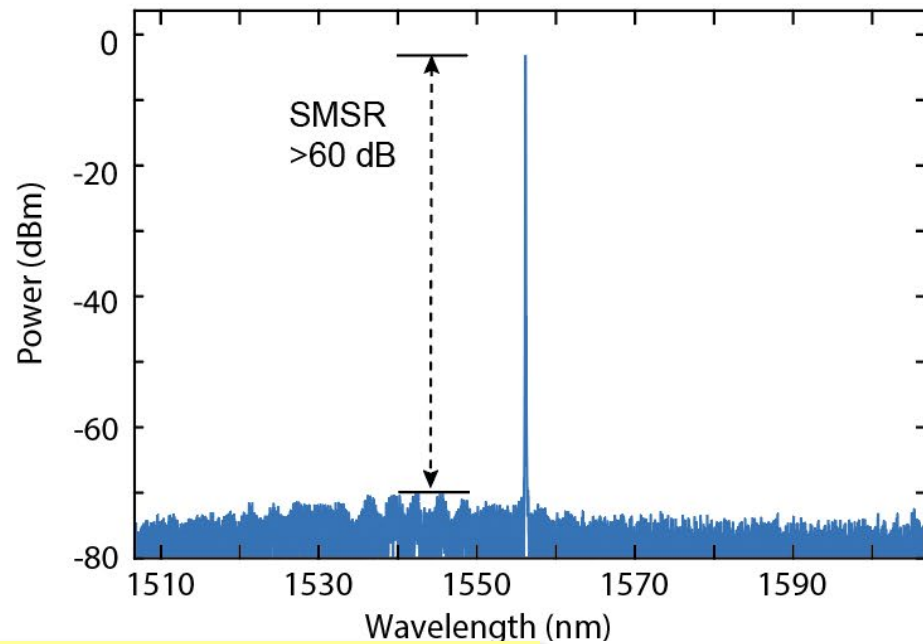
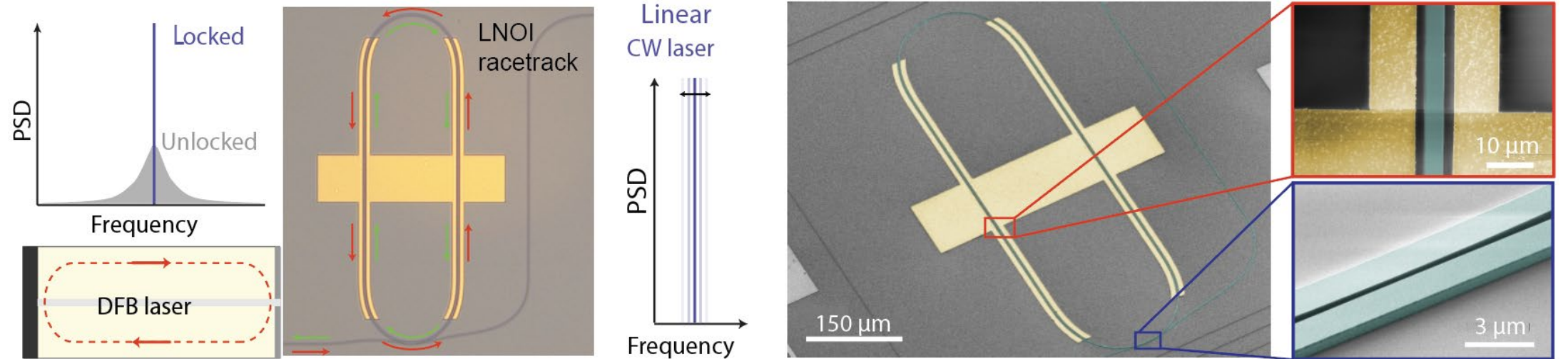
Strong electro-optical nonlinearity for ultrafast modulators & datacenter applications

Wafer-scale fabrication process:

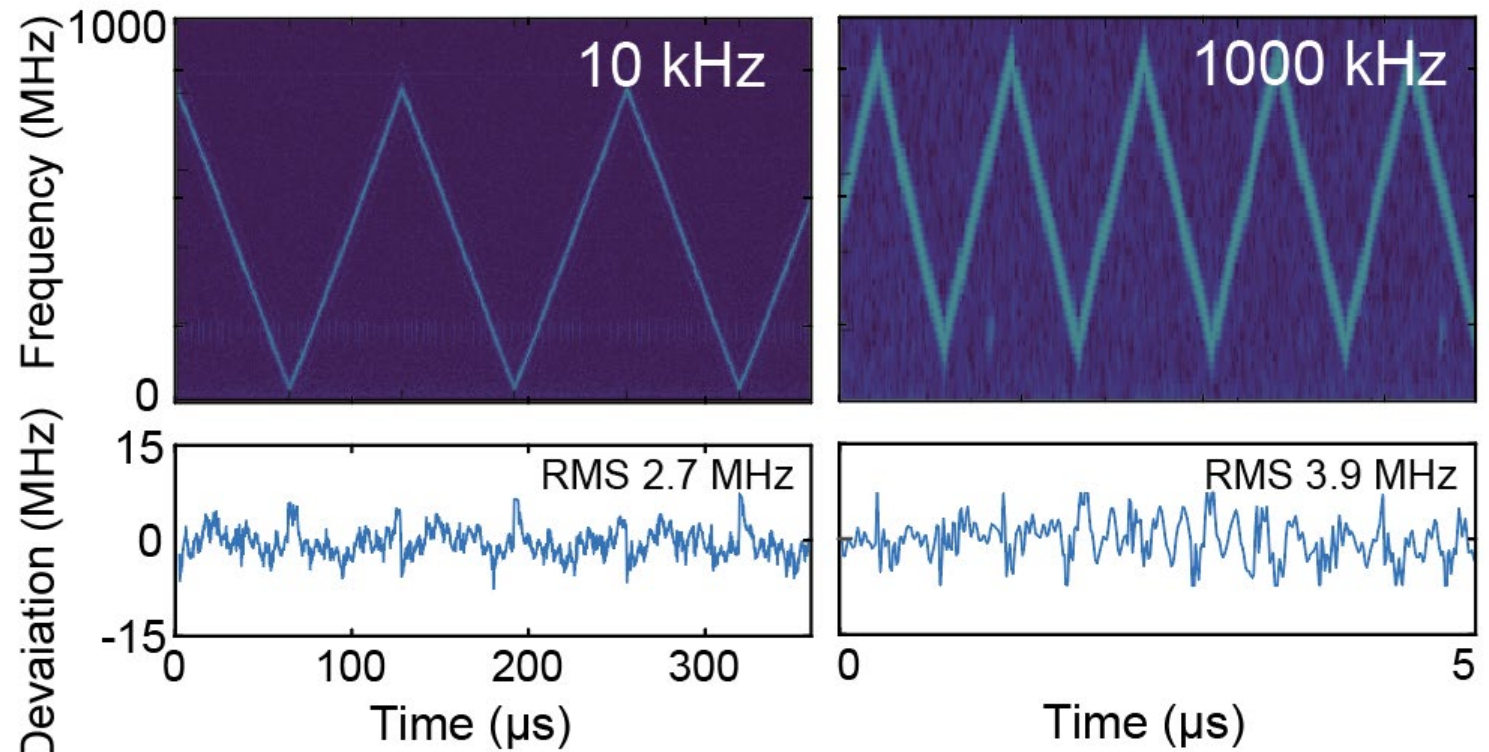
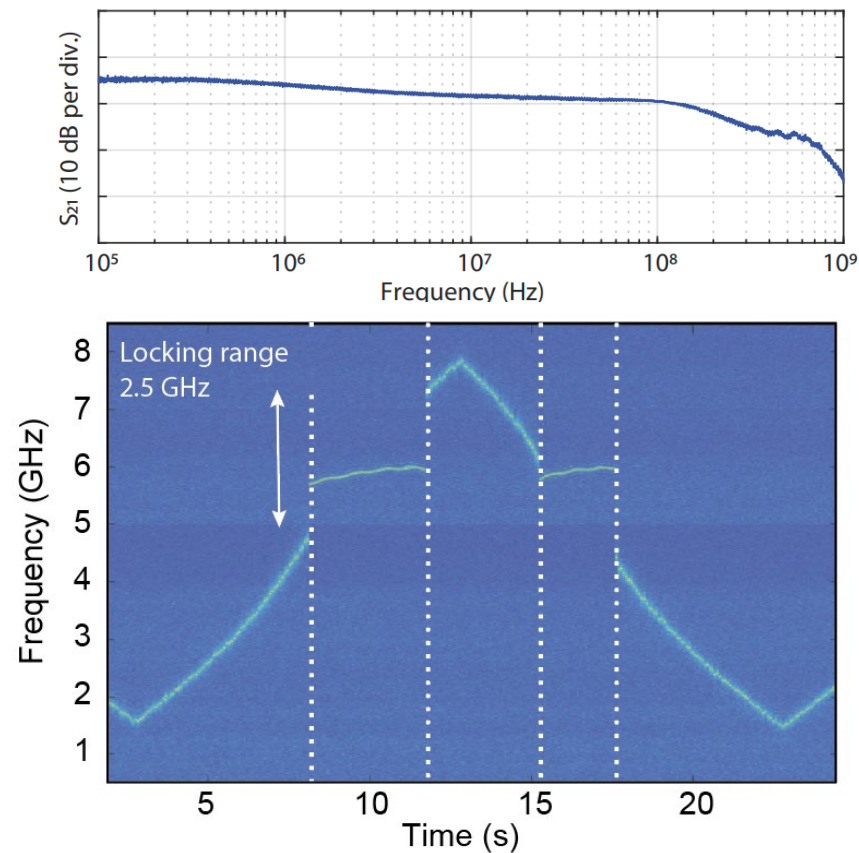
- Optical propagation loss < 0.12 dB/cm across full wafer
- Best propagation loss < 0.05 dB/cm



Self-injection locked lasers based on LNOI



Frequency-agile operation of LNOI laser



Frequency-agile operation of self-injection locked laser:





- Locking range > 2.5 GHz, > 10 kHz intrinsic optical laser linewidth
- Linear chirping at MHz rates w/o predistortion (RMS < 0.5%) at CMOS compatible voltages (950 MHz/V)

Thank you for your attention!

- Tobias Kippenberg
- Johann Riemensberger
- Rui Ning Wang
- Andrea Bancora
- Andrey Voloshin
- Grigorii Likhachev
- Viacheslav Snigirev
- Yang Liu
- Hao Tian
- Arslan S. Raja
- Junqiu Liu



Main Collaborators:

Sunil Bhawe Christian Koos

